

Exceptional Morphology-Preserving Evolution of Formamidinium Lead Triiodide Perovskite Thin Films via Organic-Cation Displacement

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Supporting Information

ABSTRACT: Here we demonstrate a radically different chemical route for the creation of $\text{HC}(\text{NH}_2)_2\text{PbI}_3$ (FAPbI_3) perovskite thin films. This approach entails a simple exposure of as-synthesized $\text{CH}_3\text{NH}_3\text{PbI}_3$ (MAPbI_3) perovskite thin films to $\text{HC}(=\text{NH})\text{NH}_2$ (formamidine or FA) gas at 150 °C, which leads to rapid displacement of the MA^+ cations by FA^+ cations in the perovskite structure. The resultant FAPbI_3 perovskite thin films preserve the microstructural morphology of the original MAPbI_3 thin films exceptionally well. Importantly, the myriad processing innovations that have led to the creation of high-quality MAPbI_3 perovskite thin films are directly adaptable to FAPbI_3 through this simple, rapid chemical-conversion route. Accordingly, we show that efficiencies of perovskite solar cells fabricated with FAPbI_3 thin films created using this route can reach ~18%.

Thin films of organic–inorganic halide perovskites have been studied extensively as light-absorbing materials, which are at the heart of perovskite solar cells (PSCs).^{1–3} The unique combination of low-cost processing^{2,3} and high power-conversion efficiencies (PCEs),⁴ rivaling those of conventional Si-based solar cells, holds out great promise for PSCs. While methylammonium lead triiodide ($\text{CH}_3\text{NH}_3\text{PbI}_3$ or MAPbI_3) perovskite,¹ with a bandgap of ~1.55 eV, is the most widely studied, there is growing interest in formamidinium lead triiodide ($\text{HC}(\text{NH}_2)_2\text{PbI}_3$ or FAPbI_3) perovskite.^{5–7} This is primarily due to its smaller band gap (~1.45 eV)⁵ and inherently superior thermal stability.⁶ Since the morphology of perovskite thin films plays a central role in the performance of PSCs, unprecedented effort has been devoted to controlling the thin-film uniformity and/or to tailoring the perovskite microstructures, with particular emphasis on MAPbI_3 perovskite.^{2,3} However, the development of effective protocols for the morphological engineering of FAPbI_3 perovskite thin films, and their microstructural tailoring, is lagging,² which is associated with the following. First, the “ionic radius” of FA^+ cation (2.53 Å) is larger than that of MA^+ cation (2.17 Å),⁸ and the symmetries of FA^+ and MA^+ cations are quite different,⁹ both of which are expected to affect the growth kinetics of FAPbI_3 perovskite. Second, FAPbI_3 also crystallizes in a “yellow” nonperovskite polymorph ($\delta\text{-FAPbI}_3$), often as a byproduct

during FAPbI_3 perovskite crystallization, which is undesirable.⁷ Therefore, manipulating the formation of FAPbI_3 perovskite thin film requires stricter control over the synthetic procedures, which is a major hurdle in the path of realizing its full potential in PSCs.

Typically, hybrid perovskite thin films evolve from the reaction between their organic and inorganic halide precursor phases through “one-step” or “two-step” synthetic processes.^{2,3} Myriad innovations in this regard have been reported in the context of the formation of MAPbI_3 perovskite thin films with desirable morphologies and microstructural characteristics.^{1–3} Thus, there is an unprecedented opportunity to take advantage of these significant advances, where the MAPbI_3 perovskite phase in the thin film is converted directly to FAPbI_3 perovskite phase while preserving the desirable morphologies and microstructures of the original thin film. Ion-exchange reaction¹⁰ of $\text{MAPbI}_3 + \text{FA}^+ \leftrightarrow \text{FAPbI}_3 + \text{MA}^+$ may be a possible strategy for the phase conversion. However, there are two intrinsic issues with this strategy: (i) ion-exchange reaction is highly reversible,¹⁰ which makes control of the forward reaction kinetically challenging, and (ii) in order to conduct this reaction at ambient pressure, the protonated formamidine (FA^+) generally requires to be dissolved in an alcohol solvent that also dissolves the perovskite phases, affecting the film morphologies. As a result, the conversion of a smooth MAPbI_3 perovskite thin film to FAPbI_3 using ion exchange leads to a dramatic change in the film morphology in the final film (see Figure S1 in Supporting Information (SI)). This is consistent with reports on ion-exchange-based perovskite interconversion.^{11,12}

These above issues have motivated us to discover a low-reversibility reaction route, without the use of detrimental solvents, for realizing morphology-preserving $\text{MAPbI}_3 \rightarrow \text{FAPbI}_3$ perovskite conversion. Here, we show that the use of the following single-cation displacement reaction, which can be considered as a redox reaction,¹³ is a feasible strategy:



Reaction 1 is also depicted in the top section of Figure 1, which involves the reduction of MA^+ into methylamine (CH_3NH_2 or MA) and the oxidation of formamidine

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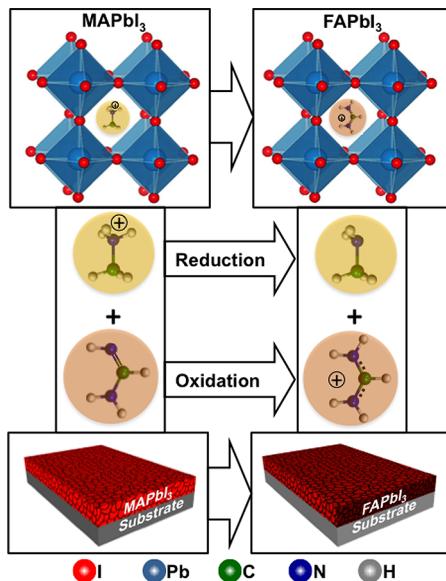


Figure 1. Cation displacement reaction between MAPbI_3 perovskite and $\text{HC}(=\text{NH})\text{NH}_2$ (formamidine or FA) gas at 150°C resulting in FAPbI_3 perovskite and CH_3NH_2 (methylamine or MA) gas, and schematic illustration depicting morphology-preserving $\text{MAPbI}_3 \rightarrow \text{FAPbI}_3$ perovskite thin-film conversion.

($\text{HC}(=\text{NH})\text{NH}_2$ or FA) into FA^+ . (For the sake of brevity MA^+ (or FA^+) is considered as a single cation and MA (or FA) its elementary form.) As shown schematically in Figure 1 (bottom), simply exposing an as-deposited MAPbI_3 perovskite thin film to gaseous FA (150°C , 4 min) completes the rapid $\text{MAPbI}_3 \rightarrow \text{FAPbI}_3$ conversion while retaining the thin-film morphology. The detailed experimental procedures are included in SI. In the experimental setup (Figure S2), the gaseous FA (boiling point $\sim 90^\circ\text{C}$)¹⁴ is produced by reacting formamidine acetate salt with sodium hydroxide at 150°C and purified by passing through a CaO desiccant. The as-produced hot FA gas fills the experimental chamber and then reacts with the predeposited MAPbI_3 thin film. Partial or full conversion of MAPbI_3 to FAPbI_3 is achieved by performing the reaction for specific durations (up to 4 min). As expected, the back-conversion of the as-converted FAPbI_3 thin films to MAPbI_3 is very sluggish in MA atmosphere using the similar experimental setup/condition (Figure S3), confirming the limited reversibility of reaction 1.

To validate the unique “morphology-preservation” feature of the $\text{MAPbI}_3 \rightarrow \text{FAPbI}_3$ perovskite conversion process via organic-cation displacement, four different starting MAPbI_3 thin films were prepared using four different methods reported in the literature, viz. one-step spin-coating,^{1,15} sequential deposition,¹⁶ antisolvent treatment,¹⁷ and MA-gas treatment.¹⁸ These MAPbI_3 films exhibit rather distinct morphologies (Figure 2A,C,E,G) at micro/nanoscales. As reported in the literature, the MAPbI_3 perovskite films prepared using one-step spin-coating contains 1D branch-like structures,¹⁵ the two-step dipping method results in 3D cuboids,¹⁶ and the antisolvent/MA-gas treatments^{17,18} lead to smooth polycrystalline thin films. These morphological characteristics can meet different functional requirements in the devices, which has been demonstrated extensively in the literature. Remarkably, after the organic-cation displacement reaction (reaction 1), the morphologies of the resultant films (Figure 2B,D,F,H) simply mimic those of the original MAPbI_3 films in all the cases. A

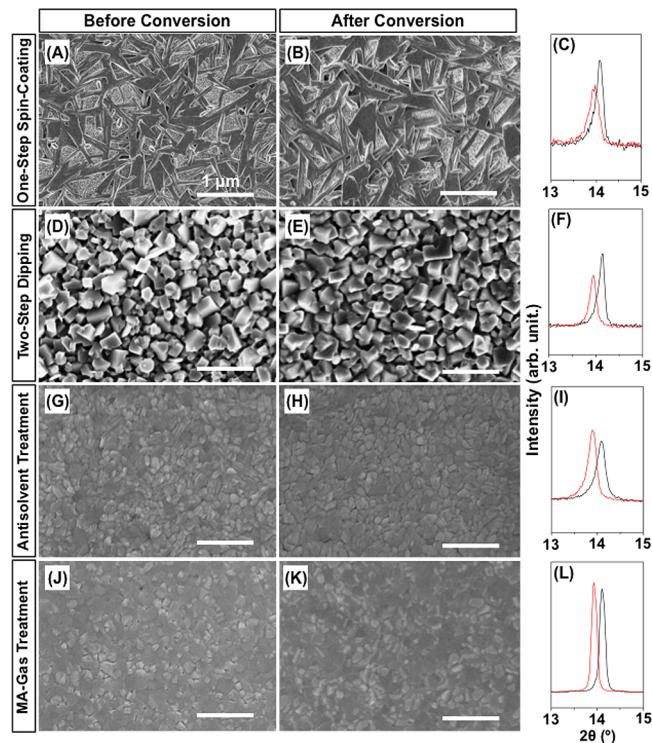


Figure 2. SEM micrographs (top view) of the MAPbI_3 perovskite thin films deposited using (A) one-step spin-coating, (D) two-step dipping, (G) antisolvent treatment, and (J) MA-gas treatment. SEM micrographs of the corresponding converted FAPbI_3 perovskite thin films (FA gas, 150°C , 5 min): (B), (E), (H), and (K). Corresponding XRD patterns (black: MAPbI_3 (before); red: FAPbI_3 (after)): (C), (F), (I), and (L).

closer look at the XRD patterns of these films before and after the conversion reveals that the XRD peaks at $2\theta \sim 14.1^\circ$ for MAPbI_3 have shifted to a lower angle of $\sim 13.9^\circ$ for FAPbI_3 (Figure 2C,F,I,L). Consistent with this observation, the characteristic XRD peaks also shift from $\sim 28.4^\circ$ to 28.1° (Figure S4A–D) in all cases. This confirms the conversion of MAPbI_3 to FAPbI_3 perovskite.⁷ Note that the small variations in the peak positions between the four cases may be related to the variations in film crystallinity.¹⁹ Also note that the XRD peak corresponding to the FTO substrate stays the same before and after the conversion (Figure S4), as expected. The success of this FA-gas-induced $\text{MAPbI}_3 \rightarrow \text{FAPbI}_3$ phase conversion, while preserving the thin-film morphology, can be attributed to the following. First, MAPbI_3 exhibits cubic crystalline structure (space group $Pm\bar{3}m$)²⁰ at elevated temperature (150°C) with a lattice parameter $a = 6.31\text{ nm}$, while FAPbI_3 also has a cubic, or a pseudocubic, crystal structure (space group $Pm\bar{3}m$ ²¹ or $Pm31$ ²⁰) with $a = 6.36\text{ nm}$. This inherent structural similarity favors $\text{MAPbI}_3 \rightarrow \text{FAPbI}_3$ conversion. Second, there is a very small difference ($\sim 0.2\%$) between the densities of MAPbI_3 (4.092 g.cm^{-3}) and FAPbI_3 (4.101 g.cm^{-3})²⁰ precluding any issues associated with volume change during the $\text{MAPbI}_3 \rightarrow \text{FAPbI}_3$ conversion.

In order to understand the mechanism underlying the conversion process, X-ray diffraction (XRD) patterns are presented in Figure 3A,B showing the progression of reaction 1 at $t = 1\text{--}4\text{ min}$ of FA-gas treatment at 150°C . A shift of the peaks to lower 2θ with progressive conversion is observed in Figure 3A. Figure 3B shows the details of the XRD patterns in

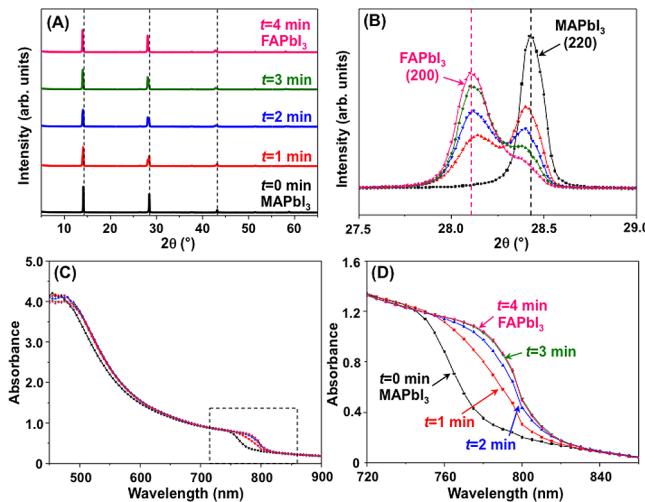


Figure 3. XRD patterns of FA-gas-treated ($150\text{ }^{\circ}\text{C}$) thin films for $t = 0\text{--}4$ min. The dashed lines mark the peak positions of MAPbI₃ perovskite. (B) Higher-resolution XRD patterns (overlaid) of thin films corresponding to those in (A). Dashed lines mark the MAPbI₃ (220) and FAPbI₃ (200) perovskite peak positions, respectively. (C) Optical absorption spectra of the FA-gas-treated ($150\text{ }^{\circ}\text{C}$) thin films for $t = 0$ to 4 min. (D) Details of the optical absorption spectra marked by the dashed rectangle in (C).

the 2θ range $27.50\text{--}29.00^{\circ}$. The presence of phase-pure MAPbI₃ perovskite at $t = 0$ min is confirmed by the presence of the 220 reflection at $2\theta = 28.42^{\circ}$. With exposure to FA gas, the FAPbI₃ perovskite 200 reflection starts to appear centered around $2\theta = 28.10^{\circ}$. With increasing FA-gas treatment duration, the intensity of the FAPbI₃ perovskite 200 reflection increases, whereas the MAPbI₃ 220 reflection decreases. At $t = 4$ min, the MAPbI₃ \rightarrow FAPbI₃ conversion is nearly complete. It is encouraging that the formation of the undesirable “yellow” nonperovskite FAPbI₃ phase and decomposition of perovskite into PbI₂ phase are both suppressed during the conversion process, which could be related to the fact that FAPbI₃ perovskite phase is thermodynamically more stable at the reaction temperature ($150\text{ }^{\circ}\text{C}$). The overall phase-conversion kinetics are more than an order-of-magnitude faster than the ion-exchange process reported by Eperon et al.¹² involving the use of solvents. In fact, such rapid conversion kinetics are responsible for the fundamentally different conversion mechanism in our cation-displacement process. In the ion-exchange process, the perovskite conversion progresses by gradual alloying of FA⁺ into MAPbI₃, until an equilibrium in the solid–liquid system is reached, with a FA⁺-rich perovskite alloy (FA_xMA_{1-x}PbI₃) as the final product. The sluggish reaction kinetics allows sufficient time for the mixing of the FA⁺ and MA⁺ across the entire film. Correspondingly, the XRD patterns of the partially converted films show symmetric diffraction peaks, indicative of the formation of homogeneous single-phase FA_xMA_{1-x}PbI₃ alloys.¹² However, in our cation-displacement process, the reaction is much faster, and, thus, a heterogeneous two-phase mixture of MAPbI₃ and FAPbI₃ is observed in the partially converted perovskite film instead, and the reaction progresses until the MAPbI₃ phase is depleted. Figure 3C,D show optical-absorption spectra for the films at $t = 0\text{--}4$ min of FA-gas treatment at $150\text{ }^{\circ}\text{C}$, corresponding to the XRD patterns in Figure 3A,B. While the absorbance at low wavelengths in all the thin films is virtually indistinguishable, at longer wavelengths the extension of absorbance into near-

infrared (NIR) region is clearly seen in Figure 3C. Figure 3D shows details of the absorption spectra in the NIR range, where the absorption is extended by ~ 30 nm into the NIR after conversion. The partially converted films show mixed absorption feature of MAPbI₃ and FAPbI₃ perovskite thin films. This is consistent with the XRD results in Figure 3A,B.

This morphology-preserving MAPbI₃ \rightarrow FAPbI₃ conversion can find promising application in the fabrication of high-efficiency FAPbI₃ PSCs. To demonstrate this, a dense, full-coverage MAPbI₃ perovskite thin film was first deposited upon a 250 nm mesoporous TiO₂/compact-TiO₂/FTO anode using the MA-gas treatment method described elsewhere,¹⁸ where the uniform morphology of that thin film is clearly evident in Figure 4A (cross-section). After conversion, the morphology/

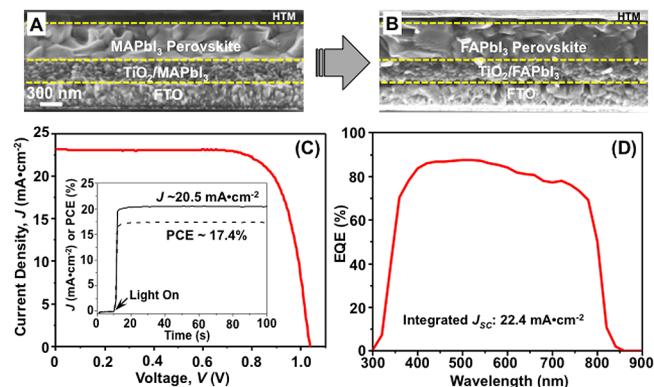


Figure 4. Cross-sectional SEM micrographs: (A) MAPbI₃ perovskite thin film and (B) converted FAPbI₃ perovskite thin film. (C) $J\text{-}V$ response of the best FAPbI₃-based PSC (inset: stabilized J and PCE output at maximum power point) and (D) corresponding EQE spectrum.

microstructure of the mesostructured TiO₂/FAPbI₃ perovskite and the FAPbI₃ perovskite capping-layers appears indistinguishable from the original MAPbI₃ thin film (Figure 4B). The morphology preservation is further confirmed by comparing the surface morphologies of the perovskite layers before and after conversion, as shown in Figure S5. The fabrication of the FAPbI₃-based PSCs was then completed by depositing Spiro-OMeTAD/Au cathode. Figure 4A shows the reverse-scan current density–voltage ($J\text{-}V$) response of the best PSC under one-sun illumination, showing PCE of 18.1% with short circuit current density (J_{SC}) of 22.3 mA cm^{-2} , open circuit voltage (V_{OC}) of 1.04 V , and fill factor (FF) of 0.75. Since typical $J\text{-}V$ hysteresis is observed regardless of the scan rate (Figure S6), the maximum power point current/power output was monitored, showing a stabilized PCE of 17.4% (inset in Figure 4C). The most impressive performance parameter of the FAPbI₃ PSC is the high J_{SC} of 23.2 mA cm^{-2} , which is consistent with the integrated J_{SC} of 22.4 mA cm^{-2} obtained from the corresponding external quantum efficiency (EQE) spectrum in Figure 4D. This is clearly due to the extended absorption into the NIR region of the solar spectrum, compared to our previously studied MAPbI₃ PSCs,¹⁸ due to the smaller bandgap of the FAPbI₃. Also, excellent reproducibility of the cation-displacement approach is evinced by the PSC performance parameters statistics in Table S1. Furthermore, using a planar polycrystalline MAPbI₃ thin film (via the antisolvent treatment method) as the starting film, the FAPbI₃ perovskite thin film from this cation-displacement conversion

process yields a PCE of ~17% with a high J_{SC} of 22.2 mA cm⁻² (Figure S7), which attests to the versatility of this method. These results show that the high quality of the starting MAPbI₃ perovskite thin films can be preserved in the resultant FAPbI₃ perovskite thin films during the FA-gas-induced conversion, which leads to the high performance in the FAPbI₃-perovskite-based PSCs.

In closing, the unprecedented organic-cation displacement approach presented here is very attractive for the processing of high-performance FAPbI₃-based PSCs and other types of devices, as it combines synergistically the clear advantage of high-quality MAPbI₃ perovskite thin-films deposition protocols and the desirable attributes of the FAPbI₃ perovskite. This approach has generic appeal, and it could be extended to the synthesis of other compounds (e.g., FASnI₃).

■ ASSOCIATED CONTENT

Supporting Information

The Supporting Information is available free of charge on the ACS Publications website at DOI: [10.1021/jacs.6b02787](https://doi.org/10.1021/jacs.6b02787).

Experimental details and data ([PDF](#))

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Notes

The authors declare no competing financial interest.

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